Supplementary Information

A High-Performance Non-fullerene Electron Acceptor with Bisalkylthiothiophene π-Bridges for Organic Photovoltaics

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1. Materials and synthesis

All reagents and solvents were purchased from commercial sources and used without further purification unless stated otherwise. 3,4-Dimethoxythiophene 1, (4,4,9,9-tetrakis(4-hexylphenyl)-4,9-dihydro-s-indaceno[1,2-b:5,6-b’]dithiophene-2,7-diyl)bis(trimethylstannane) 5, and the end-capping groups were purchased from SunaTech Inc. Compounds 2, 3 and 4 were synthesized according to the literature.\(^1\) PBDB-T (number-average molecular weight: 25.0 kDa, polydispersity index: 2.36) and PDINO were purchased from Solarmer Materials and SunaTech Inc, respectively.

**Scheme S1** Synthetic routes to the bisalkylthiothiophene-based π bridge and IDT2ST-4F.

**Compound 2:** A mixture of 3,4-dimethoxythiophene 1 (2.5 g, 17.3 mmol) with 5 equivalents of 1-mercaptooctane (12.69 g, 86.5 mmol) and a catalytic amount of p-toluenesulfonic acid (0.2 g) in dry toluene (50 mL) was stirred for 16 h at 80 °C under a flow of nitrogen. After cooling down, toluene was removed under reduced pressure and the residue was diluted with water (200 mL). The mixture was extracted with dichloromethane (100 mL × 2) and the organic layer was washed with dilute NaHCO\(_3\) aqueous solution and brine, dried over anhydrous MgSO\(_4\). The solvent was removed by rotary evaporation and subsequently dried in a vacuum oven. The crude product was purified by column chromatography on silica gel using...
dichloromethane/petroleum ether (1:10, v/v) to afford 2 as a colorless liquid (2.4 g, 60%). $^1$H NMR (500 MHz, CDCl$_3$) $\delta$ (ppm): 7.11 (s, 2H), 2.91 – 2.86 (t, $J = 7.4$ Hz 4H), 1.66 (m, 4H), 1.49 – 1.39 (m, 4H), 1.29 (m, 16H), 0.90 (t, $J = 6.9$ Hz, 6H). $^{13}$C NMR (126 MHz, CDCl$_3$) $\delta$ (ppm): 133.99, 122.89, 34.42, 31.83, 29.20, 29.18, 29.02, 28.84, 22.67, 14.11.

**Compound 3:** POCl$_3$ (4 mL) was added dropwise to DMF (1 mL) at 0 °C with the protection of argon. The solution turned into a glue and the color turned into light yellow after stirred for 30 min at room temperature. Then a solution of 2 (1 g, 2.7 mmol) in dry 1,2-dichloroethane (CH$_2$Cl$_2$CH$_2$Cl, 30 mL) was added to the mixture quickly. After stirred and refluxed for 16 h at 70 °C with the protection of argon, the reaction mixture was cooled to room temperature and washed with brine. Then the solution was extracted with dichloromethane (100 mL × 2) and dried over anhydrous MgSO$_4$. The solvent was removed by rotary evaporation, and the crude product was purified by column chromatography on silica gel using dichloromethane/petroleum ether (1:20, v/v) to afford 3 as a pale-yellow oil (800 mg, 75%). $^1$H NMR (500 MHz, CDCl$_3$) $\delta$ (ppm): 10.16 (d, $J = 1.2$ Hz, 1H), 7.28 (d, $J = 1.1$ Hz, 1H), 2.86 (m, 4H), 1.68 – 1.56 (m, 2H), 1.51 – 1.42 (m, 2H), 1.42 – 1.34 (m, 2H), 1.33 – 1.27 (m, 2H), 1.27 – 1.11 (m, 16H), 0.81 (t, $J = 6.9$ Hz, 6H). $^{13}$C NMR (126 MHz, CDCl$_3$) $\delta$ (ppm): 184.34, 145.12, 140.95, 140.48, 127.68, 36.30, 33.75, 31.79, 31.76, 29.66, 29.16, 29.14, 29.05, 28.90, 28.76, 28.52, 22.64, 22.62, 14.09, 14.08.

**Compound 4:** A solution of 3 (2 g, 5.0 mmol) in dichloromethane (40 mL) was stirred at 0 °C while $n$-bromosuccinimide (NBS) (0.98 g, 5.5 mmol) was added portion-wise. The reaction mixture was raised to room temperature and maintained at this temperature for 16 h. Then the mixture was poured into ice water (200 ml) and extracted with CH$_2$Cl$_2$ (100 mL × 2), dried over anhydrous MgSO$_4$. The solvent was removed by rotary evaporation. The crude product was purified by column chromatography on silica gel using dichloromethane/petroleum ether (1:10, v/v) as eluant to afford 4 as a pale-yellow oil (1.8 g, 78%). $^1$H NMR (500 MHz, CDCl$_3$) $\delta$ (ppm): 10.09 (s, 1H), 2.94 (t, $J = 7.3$ Hz, 2H), 2.82 (t, $J = 7.3$ Hz, 2H), 1.50 – 1.43 (m, 4H), 1.36 – 1.28 (m, 4H), 1.25 – 1.44 (m, 16H), 0.80 (t, $J = 6.9$ Hz, 6H). $^{13}$C NMR (126 MHz, CDCl$_3$) $\delta$ (ppm): 183.20, 145.42, 144.89, 138.72, 130.97, 36.99, 35.81, 31.79, 31.75, 29.62, 29.59, 29.16, 29.14, 29.05, 28.61, 28.55, 22.64, 22.62, 14.09, 14.08.
**Compound 6:** A solution of 5 (2 g, 1.6 mmol) and 4 (3.8 g, 8 mmol) in dry toluene (100 ml) was degassed twice with argon following the addition of Pd(PPh\(_3\))\(_4\) (0.9 g, 0.8 mmol). After stirred and refluxed for 24 h at 110 °C with the protection of argon, the reaction mixture was poured into water (100 mL) and extracted with CH\(_2\)Cl\(_2\) (100 mL x 2). The organic layer was washed with water for twice and dried over anhydrous MgSO\(_4\). After removal of the solvent, the crude product was purified by silica gel using dichloromethane/petroleum ether (1:1) as eluant to afford 6 as a red solid (1.90 g, 70%). \(^1\)H NMR (500 MHz, CDCl\(_3\)) \(\delta\) (ppm): 10.12 (s, 2H), 7.51 (s, 2H), 7.43 (s, 2H), 7.10 (d, \(J = 8.3\) Hz, 8H), 7.01 (d, \(J = 8.3\) Hz, 8H), 2.92 (t, \(J = 7.4\) Hz, 4H), 2.82 – 2.70 (t, \(J = 7.5\) Hz, 4H), 2.57 – 2.40 (t, \(J = 7.8\) Hz, 8H), 1.66 – 1.37 (m, 20H), 1.27 – 1.05 (m, 50H), 0.87 – 0.70 (m, 24H). \(^{13}\)C NMR (126 MHz, CDCl\(_3\)) \(\delta\) (ppm): 183.91, 155.90, 154.10, 149.47, 147.80, 145.50, 141.85, 141.31, 140.46, 137.33, 135.59, 131.61, 128.49, 127.82, 124.36, 118.03, 62.99, 37.30, 36.93, 35.59, 31.75, 31.37, 29.64, 29.27, 28.88, 28.62, 22.62, 14.10. MS (MALDI-TOF): calcd for C\(_{106}\)H\(_{142}\)O\(_2\)S\(_8\) [M\(^+\)] 1703.8809; found: 1703.8848.

**IDT2ST-4F:** 6 (0.57 g, 0.3 mmol) and 2-(5,6-difluoro-3-oxo-2,3-dihydro-1H-inden-1-ylidene)malononitrile 7a (0.21 g, 0.9 mmol) was dissolved in a dry CHCl\(_3\) (50 ml) solution under the protection of argon, and then three drops of pyridine were added to the mixture. After stirred at room temperature for 16 h, the mixture was extracted with CHCl\(_3\) (50 ml x 2), and the organic layer was washed with water and dried over anhydrous MgSO\(_4\) for 3 h. After removal of the solvent, the crude product was purified by silica gel using dichloromethane/petroleum ether (1:10) as eluant to afford **IDT2ST-4F** (0.59 g, 83%) as a black solid. \(^1\)H NMR (500 MHz, CDCl\(_3\)) \(\delta\) (ppm): 9.44 (s, 2H), 8.49 (m, 2H), 7.72 (s, 2H), 7.61 (t, \(J = 7.5\) Hz, 2H), 7.43 (s, 2H), 7.13 (d, \(J = 8.3\) Hz, 8H), 7.04 (d, \(J = 8.4\) Hz, 8H), 3.00 – 2.91 (t, \(J = 7.5\) Hz, 4H), 2.86 – 2.75 (t, \(J = 7.5\) Hz, 4H), 2.57 – 2.45 (t, \(J = 7.8\) Hz, 8H), 1.60 – 1.45 (m, 20H), 1.35 – 1.19 (m, 40H), 1.19 – 1.10 (m, 30H), 0.78 (m, 24H). \(^{13}\)C NMR (126 MHz, CDCl\(_3\)) \(\delta\) (ppm): 186.02, 158.61, 156.96, 154.87, 153.98, 148.10, 142.02, 140.98, 137.80, 136.63, 135.98, 134.74, 133.56, 128.60, 127.92, 125.53, 122.35, 118.36, 114.88, 114.51, 113.88, 112.73, 112.57, 70.65, 63.07, 35.62, 31.80, 31.75, 31.41, 29.20, 29.17, 29.16, 29.16, 29.12, 29.11, 28.92, 28.80, 22.65, 22.62, 22.61, 14.13, 14.10. MS (MALDI-TOF): calcd for C\(_{130}\)H\(_{146}\)F\(_4\)N\(_4\)O\(_2\)S\(_8\) [M\(^+\)] 2129.1; found: 2128.9.

2. **Instruments and general methods**
$^1$H-NMR and $^{13}$C-NMR spectra were recorded on a Bruker AVANCE 500 spectrometer. Mass spectra (MS) were recorded on a Walters MALDI Q-TOF Premier mass spectrometry. Thermogravimetric analysis (TGA) and differential scanning calorimetric (DSC) measurements were carried out on a TA Q500 and a NETZSCH DSC 214 instrument under nitrogen gas flow with a 10 °C min$^{-1}$ heating rate, respectively. UV-vis absorption spectra were obtained with double-beam Hitachi UH5300 spectrophotometer. Cyclic voltammetry (CV) measurements were conducted with the films on the glassy carbon working electrode in dry dichloromethane solution via a LK2005A electrochemical workstation. All CV measurements were carried out at room temperature with a conventional three-electrode configuration employing a glassy carbon electrode as the working electrode, a saturated calomel electrode (SCE) as the reference electrode, and a Pt wire as the counter electrode. Tetrabutylammonium phosphorus hexafluoride (Bu$_4$NPF$_6$, 0.1 M) in dichloromethane was used as the supporting electrolyte, and the scan rate was 100 mV s$^{-1}$. $E_{\text{ox on set}}$ and $E_{\text{re on set}}$ are oxidation and reduction onsets, respectively, against the half potential of ferrocene/ferrocenium (Fc/Fc$^+$), as determined in CV curves. The HOMO and LUMO energy levels were estimated by the equations: HOMO = -(4.8 + $E_{\text{ox on set}}$) eV, LUMO = -(4.8 + $E_{\text{re on set}}$) eV, respectively. Atomic force microscopy (AFM) measurements were carried out in tapping mode on a Bruker MutiMode 8 atomic force microscope. Out-of-plane XRD was measured with a Bruker D8 Advance using CuKα$_\lambda$ radiation ($\lambda=1.54056$ Å) and operated at 40 kV and 30 mA, and in-plane XRD was conducted on a Rigaku Smart Lab with CuKα source ($\lambda=1.54056$ Å).

3. Solar cell fabrication and characterization

The devices with an architecture of glass/ITO/PEDOT:PSS (40 nm)/PBDB-T:acceptor /PDINO/Al (100 nm) were fabricated. The ITO coated glass substrates were cleaned ultrasonically with detergent, deionized water, acetone and isopropanol under ultrasonication for 15 min each. The dried ITO was treated with UV-ozone for 20 min, and then solution of PEDOT:PSS (Baytron P AI 4083) was spin-coated (ca. 40 nm thick) onto the surface. The substrates were then placed into an argon-filled glove box after being baked at 150 °C for 20 min. Subsequently, the active layer was spin-coated from donor and acceptor mixture in chloroform solution on the ITO/PEDOT:PSS substrate. Subsequently, the substrate was annealed at 110 °C for 5 min. Then PDINO in CH$_3$OH (1 mg/mL), was spin-coated at 3000 rpm for 40 s on the
active layers. Finally, a 100 nm Al layer was deposited on the PDINO layer under high vacuum (< 1.5 × 10^{-4} Pa). The effective area of each cell is 4 mm², as defined by masks for the solar cell devices. Keithley 2400 source meter was used to measure $J-V$ curves under 100 mW cm⁻² AM 1.5G simulated solar light illumination provided by an AAA solar simulator (SS-F5-3A, Enli Technology Co. Ltd) calibrated with a standard photovoltaic cell equipped with a KG5 filter in a glove box. The EQE data were obtained using a solar cell spectral response measurement system (QE-R, Enli Technology Co. Ltd).

Hole-only devices with an architecture of ITO/PEDOT:PSS (40 nm)/ PBDB-T:acceptor/Au (100 nm) and electron-only devices with an architecture of glass/Al (100 nm)/PBDB-T:acceptor/Al (100 nm) were fabricated. The devices were measured using Keithley 2400 source meter in a glove box under dark. The hole and electron mobilities were calculated by fitting the dark current using the Mott-Gurney relationship:

$$J = \frac{9}{8} \varepsilon_r \varepsilon_0 \mu \frac{V^2}{L^3}$$

where $J$ is the current density, $L$ is the film thickness of the active layer, $\mu$ is the hole or electron mobility, $\varepsilon_r$ is the relative dielectric constant of the transport medium, $\varepsilon_0$ is the permittivity of free space (8.85×10^{-12} F m⁻¹), $V$ (= $V_{appl} - V_{bi}$) is the internal voltage in the device, where $V_{appl}$ is the applied voltage to the device and $V_{bi}$ is the built-in voltage due to the relative work function difference of the two electrodes.

4. Supplementary data
Fig. S1 ¹H NMR spectrum of compound 2.

Fig. S2 ¹³C NMR spectrum of compound 2.
Fig. S3 $^1$H NMR spectrum of compound 3.

Fig. S4 $^{13}$C NMR spectrum of compound 3.
Fig. S5 $^1$H NMR spectrum of compound 4.

Fig. S6 $^{13}$C NMR spectrum of compound 4.
Fig. S7 ${}^1$H NMR spectrum of compound 6.

Fig. S8 ${}^{13}$C NMR spectrum of compound 6.
Fig. S9 MALDI-TOF mass spectrum of compound 6.

Fig. S10 $^1$H NMR spectrum of IDT2ST-4F.
Fig. S11 $^{13}$C NMR spectrum of IDT2ST-4F.
**Fig. S12** MALDI-TOF mass spectrum of IDT2ST-4F.

**Fig. S13** (a) TGA and (b) DSC curves of IDT2ST-4F.
**Fig. S14** Cyclic voltammogram of IDT2ST-4F in dichloromethane with 0.1 mol L\(^{-1}\) n-Bu\(_4\)NPF\(_6\) at a scan rate of 100 mV s\(^{-1}\).

**Fig. S15** (a) Electron density distributions of HOMO and LUMO orbitals, and (b) the optimized geometry of IDT2ST-4F with ethyl groups in replacing alkyl substituents to simplify the calculations.
Fig. S16 Chemical structure of PDINO.

Photovoltaic performance

Table S1 Photovoltaic parameters of PBDB-T:IDT2ST-4F based devices with donor/acceptor weight ratio of 1:1 with thermal annealing at different temperatures for 5 min. The film thickness is about 100 nm and the solvent is chlorobenzene.

<table>
<thead>
<tr>
<th>Conditions</th>
<th>$V_{oc}$ (V)</th>
<th>$J_{sc}$ (mA/cm²)</th>
<th>FF (%)</th>
<th>PCE (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>As-cast</td>
<td>0.854</td>
<td>17.32</td>
<td>62.6</td>
<td>9.27</td>
</tr>
<tr>
<td>100 °C</td>
<td>0.845</td>
<td>18.92</td>
<td>67.8</td>
<td>10.87</td>
</tr>
<tr>
<td>110 °C</td>
<td>0.849</td>
<td>19.44</td>
<td>69.3</td>
<td>11.43</td>
</tr>
<tr>
<td>120 °C</td>
<td>0.843</td>
<td>18.73</td>
<td>67.7</td>
<td>10.69</td>
</tr>
<tr>
<td>130 °C</td>
<td>0.838</td>
<td>18.36</td>
<td>69.0</td>
<td>10.50</td>
</tr>
<tr>
<td>140 °C</td>
<td>0.829</td>
<td>18.44</td>
<td>67.5</td>
<td>10.24</td>
</tr>
</tbody>
</table>

Fig. S17 Statistical histogram of PCEs for IDT2ST-4F-based devices (over 20 devices for each case under the as-cast or TA-treated conditions).
Table S2 Summary of the photovoltaic parameters of devices based on the IDT-cored small molecule acceptors.

<table>
<thead>
<tr>
<th>Acceptor</th>
<th>$E_g$ (eV)</th>
<th>Donor</th>
<th>$V_{oc}$ (V)</th>
<th>$J_{sc}$ (mA cm$^{-2}$)</th>
<th>FF (%)</th>
<th>PCE (%)</th>
<th>Ref</th>
</tr>
</thead>
<tbody>
<tr>
<td>IDTT2F</td>
<td>1.46</td>
<td>PBDB-T</td>
<td>0.81</td>
<td>18.51</td>
<td>59</td>
<td>8.85</td>
<td>2</td>
</tr>
<tr>
<td>IDTCN-S</td>
<td>1.48</td>
<td>PBDB-T</td>
<td>0.85</td>
<td>19.04</td>
<td>65.7</td>
<td>10.60</td>
<td>3</td>
</tr>
<tr>
<td>ACS8</td>
<td>1.30</td>
<td>PTB7-Th</td>
<td>0.75</td>
<td>25.3</td>
<td>69.3</td>
<td>13.2</td>
<td>4</td>
</tr>
<tr>
<td>IEICO-4F</td>
<td>1.24</td>
<td>PBDB-T</td>
<td>0.77</td>
<td>20.10</td>
<td>56</td>
<td>8.66</td>
<td>5</td>
</tr>
<tr>
<td>IDTCN-O</td>
<td>1.53</td>
<td>PBDB-T</td>
<td>0.91</td>
<td>19.96</td>
<td>73.2</td>
<td>13.28</td>
<td>3</td>
</tr>
<tr>
<td>ITOIC-2F</td>
<td>1.45</td>
<td>PBDB-T</td>
<td>0.897</td>
<td>21.04</td>
<td>64.5</td>
<td>12.17</td>
<td>6</td>
</tr>
<tr>
<td>IDT2ST-4F</td>
<td>1.43</td>
<td>PBDB-T</td>
<td>0.849</td>
<td>19.44</td>
<td>69.3</td>
<td>11.43</td>
<td>This work</td>
</tr>
</tbody>
</table>

Fig. S18 Absorption spectra of the as-cast or TA-treated pristine IDT2ST-4F films (a) and PBDB-T:IDT2ST-4F films (b).
**Fig. S19** Dependence of $V_{oc}$ on the light intensity ($P_{light}$) of the TA-treated IDT2ST-4F-based devices.

**Fig. S20** (a) In-plane and (b) out-of-plane XRD pattern of the as-cast and TA-treated IDT2ST-4F film.

**Fig. S21** $J-V$ characteristics of the hole-only (a) and electron-only (b) devices based on the PBDB-T:IDT2ST-4F blend films under different conditions.
References